PDIUSBP11

FEATURES

- Utilizes digital inputs and outputs to transmit and receive USB cable data
- Supports 12Mbit/s "Full Speed" and 1.5Mbit/s "Low Speed" serial data transmission
- Compatible with the VHDL "Serial Interface Engine" from USB developer's conference
- Available in SO, 14 pin package
- Hysteresis on D+, D-, V_{MO} inputs

DESCRIPTION

The PDIUSBP11 is a one chip generic USB transceiver. It is designed to allow 5.0V or 3.3V programmable and standard logic to interface with the physical layer of the Universal Serial Bus. It is capable of transmitting and receiving serial data at both full speed (12Mbit/s) and low speed (1.5Mbit/s) data rates. The outputs from the serial interface engine (inputs VPO and VMO on the PDIUSBP11) are driven by the host. The gated inputs (outputs VP and VM on the PDIUSBP11) are to be decoded by the host.

Implementation of the Serial Interface Engine along with the USB transceiver allow the designer to make flexible USB compatible devices with widely available logic components.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-pin plastic SO	0°C to +70°C	PDIUSBP11 D	PDIUSBP11 D	SOT108-1
14-pin plastic SSOP	0°C to +70°C	PDIUSBP11 DB	PDIUSBP11 DB	SOT337-1
14-pin plastic TSSOP	0°C to +70°C	PDIUSBP11 PW	PDUSBP11 PW DH	SOT402-1

PIN CONFIGURATION



FUNCTIONAL DIAGRAM



PIN DESCRIPTION								
PIN No.	PIN SYMBOL	I/O	NAME AND FUNCTION					
3	RCV	0	Receive data. CMOS level output for USB differential input					
2	OE#	I	Output Enable. Active LOW, enables the transceiver to transmit data on the bus. When not active the transceiver is in receive mode					
	Inputs to differential driver. (Or from SIE).							
			VPO	VMO	RESULT			
12, 13	VPO, VMO	Т	0	0	SE0#			
	VIVIO		0	1	Logic "0"			
			1	0	Logic "1"			
			1	1	Undefined			
	VP, VM	0	Gated version of D– and D+. Outputs are logic "0" and logic "1". Used to detect single ended zero (SE0#), error conditions, and interconnect speed. (Inputs to SIE).					
4, 5			VP	VM	RESULT			
			0	0	SE0#			
			0	1	Full Speed			
			1	0	Low Speed			
			1	1	Error			
11, 10	D+, D–	I/O	Data+, Data–. Differential data bus conforming to the Universal Serial Bus standard.					
6	SUSPND	I	Suspend. Enables a low power state while the USB bus is inactive. While the suspnd pin is active it will drive the RCV pin to a logic "0" state.					
9	SPEED	I	Edge rate control. Logic "1" operates at edge rates for "full speed". Logic "0" operates edge rates for "low speed".					
14	V _{CC}		3.0V to 3.6V power supply					
7	GND		Ground	reference	e			
		_						

1996 May 29

PDIUSBP11

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	DC supply voltage		3.0	3.6	V
VI	DC Input voltage range		0	5.5	V
V _{I/O}	DC input range for I/O's		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air See DC and AC characteristics for individual device		0	+70	°C

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

			LIN			
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
V _{CC}	DC supply voltage		-0.5	+6.5	V	
I _{IK}	DC input diode current	V ₁ < 0	-	-50	mA	
VI	DC input voltage	Note 3	-0.5	+5.5	V	
V _{I/O}	DC input voltage range for I/O's		-0.5	V _{CC} +0.5	V	
Ι _{ΟΚ}	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	-	50	mA	
Vo	DC output voltage	Note 3	-0.5	V _{CC} +0.5	V	
Ι _Ο	DC output source or sink current for VP/VM, RCV pins	$V_{O} = 0$ to V_{CC}	-	15	mA	
Ι _Ο	DC output source or sink current for D+/D- pins	$V_{O} = 0$ to V_{CC}	-	50	mA	
I _{GND} , I _{CC}	C DC V _{CC} or GND current		-	100	mA	
T _{stg}	Storage temperature range		-60	+150	°C	
P _{tot}	Power dissipation per package				mW	

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

PDIUSBP11

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

				UNIT			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = 0°C to +70°C				
			MIN	TYP ¹	MAX		
VIH	HIGH level input	$V_{CC} = 3.0V \text{ to } 3.6V^3$		1.5	2.0	V	
V _{IL}	LOW level input	$V_{CC} = 3.0V \text{ to } 3.6V^3$	0.8	1.3		V	
R _D H	Output impedance (HIGH state)	Note 2	28	34	43	Ω	
R _D L	Output impedance (LOW state)	Note 2	28	35	51	Ω	
		$V_{CC} = 3.0V; I_{O} = 6mA$	2.2	2 2.7			
V _{OH}	HIGH level output ³	$V_{CC} = 3.0V; I_{O} = 4mA$	2.4			V	
		$V_{CC} = 3.0V; I_{O} = 100\mu A$	2.8	-		ĺ	
	LOW level output ³	$V_{CC} = 3.0V; I_{O} = 6mA$		0.3	0.8		
V _{OL}		V _{CC} = 3.0V; I _O = 4mA			0.5	V	
		$V_{CC} = 3.0V; I_{O} = 100\mu A$		-	0.2		
ICCQ	Quiescent supply current	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		330	600	μA	
I _{CCS}	Supply current in Suspend	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		- 1	65	μΑ	
I _{CCFS}	Active supply current (Full Speed)	$V_{CC} = 3.3V$		10	30	mA	
I _{CCLS}	Active supply current (Low Speed)	V _{CC} = 3.3V		2	25	mA	
lj –	Input leakage current	V_{CC} = 3.6V; V_{I} = 5.5V or GND; not for I/O pins		0.1	5	μΑ	
I _{OZ}	3-State output OFF-state current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND ²			10	μA	

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This value includes an external resistor of 24Ω 1%. See "Load D+ and D–" diagram for testing details.

3. All signals except D+ and D-.

AC CHARACTERISTICS

GND = 0V, $t_R = t_F = 3.0$ ns, $C_L = 50$ pF, $R_L = 500\Omega$, $V_{CC} = 3.3$ V

SYMBOL	PARAMETER	TEST CONDITIONS	WAVEFORMS	LIMITS					
				T _{amb} = 25°C			T _{amb} = 0°C to +70°C		
				MIN	TYP	MAX	MIN	MAX	1
tp _{LH}	VMO/VPO to D+/D-		1	0		12	0	15	ns
tp _{HL}	Full Speed		· · ·	0		12	0	15	115
t _{rise}	Rise and Fall Times		2	4		20	4	20	ns
t _{fall}	Full Speed			4		20	4	20	1 118
tp _{LH}	VMO/VPO to D+/D-		1	30		300	30	300	ns
tp _{HL}	Low Speed			30		300	30	300	
t _{rise}	Rise and Fall Times		2	75		300	75	300	ns
t _{fall}	Low Speed			75		200	75	200	
tp _{LH}	D+/D- to RCV		3			16		16	ns
tp _{HL}			5			16		20	
tp _{LH}	D+/D- to VP/VM		1			8		8	ns
tp _{HL}						8		12	113
tp _{HZ}						12		12	
tp _{ZH}	OE# to D+/D– RL = 500Ω		4			12		15	ns
tp _{LZ}			4			10		10	
tp _{ZL}						10		15	
t _{su}	Setup for SPEED		5	0					ns
V _{cr}	Crossover point	Note 1	3	1.3		2.0	1.3	2.0	V

1. The crossover point is in the range of 1.3V to 2.5V for the low speed mode with a 50pF capacitance. In the low-speed mode with a 100pF or greater capacitance, the crossover point is in the range of 1.3V to 2.0V.

PDIUSBP11

AC WAVEFORMS

 $V_{M} = 1.5V$ $V_{X} = V_{OL} + 0.3V$ $V_{Y} = V_{OH} - 0.3V$

 V_{OL} and V_{OH} are the typical output voltage drops that occur with the output load. (V_{CC} never goes below 3.0V).



Waveform 1. D+/D- to VP/VM or VPO/VMO to D+/D-



Waveform 2. Rise and Fall Times



Waveform 3. D+/D- to RCV



Waveform 4. OE# to D+/D-



Waveform 5. Setup for Speed



Load for VM/VP and RCV



Load for Enable and Disable Times



